

MAINTENANCE MANUAL

IF/AUDIO AND SQUELCH BOARD 19D417707G1,G2 AND 19D432667G1, G2, G3

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DESCRIPTION

The IF/Audio and Squelch Board (IFAS) provides 120 dB IF gain, detects audio and provides squelch control. The IFAS board operates with an IF frequency of 11.2 or 9.4 MHz depending on the operating frequency of the radio. IFAS Board 19D417707G1 or 19D432667G1 operate with an IF frequency of 11.2 MHz and are used in radios operating in the following frequency bands:

- 25 30 MHz
- 36 42 MHz
- 66 88 MHz
- 138 174 MHz
- 406 420 MHz
- 450 512 MHz

IFAS Board 19D417707G2 or 19D432667G2 operate with an IF frequency of 9.4 MHz and are used in radios operating in the 30-36 MHz and 42-50MHz frequency bands. IFAS Board 19D432667G3 operates with an IF frequency of 9.4 MHz and is used in radios operating in the 806-825 MHz frequency band.

SERVICE NOTE: IFAS Board 19D417707 uses fix-tuned coil assemblies Z601, Z602 and Z603. IFAS Board 19D432667 uses tuneable coil assemblies T602, T603 and T604.

CIRCUIT ANALYSIS

Crystal Filters, IF Amp & Limiter

The IF input from the MIF or IF Filter board is applied to a four-pole monolithic crystal filter (FL601 and FL602). The crystal filter provides additional selectivity and is followed by impedance matching network Z601/T602 and IF Amplifier IC U601. The IC amplifier provides approximately 60 dB of gain.

Final IF selectivity is provided by a two-pole crystal filter FL603. Impedance matching network Z602/T603 matches the output impedance of IF amplifier IC U601 to the input of two-pole crystal filter FL603. The IF amplifier output is metered at J601 through a metering network consisting of C644, C611, C612, CR601 and CR602. Impedance matching network Z603/T604 matches the output impedance of FL603 to the input of Limiter/Detector IC U602.

In addition to providing 60 dB of gain at the IF frequency, Limiter Detector IC U602, C619, C620

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and L603/L606 comprise a quardrature phase detector to recover the audio from the IF frequency. The quarature phase detector utilizes a 90 degree phase shift in the IF frequency to detect the audio signal. It compares the phase of the IF input at U602-4 with the same IF input frequency shifted 90 degrees at U602-2. The resultant signal varies phase linearly as the carrier signal deviates about the center frequency.

The detector output is adjusted for maximum audio output by L603/L606 and is metered at J601 through R607.

AUDIO PREAMPLIFIER

The audio preamplifier consists of transistors Q601, Q602 and Q605. It provides approximately 26 dB of gain.

The output of the Limiter\Detector is coupled to the audio preamplifier through audio level adjust control R608. R608 sets the audio input level to the preamplifier circuit.

The output of the audio preamplifier is coupled through a low pass filter (L604 and C624) to volume and squelch control high. The filter removes any IF signal remaining in the audio output of the preamplifier.

AUDIO IC

The hybrid audio IC (U604) uses a custom flipchip monolithic integrated circuit. The audio IC contains a standard EIA Channel Guard tone reject filter, a receiver de-emphasis circuit and the low level audio PA drive circuitry.

Audio from the preamplifier is coupled through the VOLUME control to pin 4 of the audio IC from P904-13 (VOL ARM). Audio at pin 4 is applied to the Channel Guard tone reject circuit, and then to the 6 dB/octave de-emphasis circuit. The filter output is coupled through C635 to the differential audio driver circuit. The output of the audio driver circuit is DC coupled to the push-pull, Class AB audio PA transistors, Q603 and Q604. The PA output is coupled through audio transformer T601 rated power to the 8 ohm loudspeaker. R619 and C637 in the transformer secondary protects the PA transistors against a

"no-load" or open circuit. Feedback from windings T601-3 and -4 determines the gain of the audio driver amplifier.

When the receiver is squelched, pin 1 of audio IC U604 is near A-, and the entire audio circuit is turned off to eliminate current drain. Pin 1 is also connected to the system board through P904-7 (RX MUTE) so that the receiver audio can be disabled by the time delay circuit in the 10 Volt regulator, and by the Channel Guard option when used.

Pins 6 and 7 are connected to the system board through P904-16 (RX PA) and P904-21 (INTCM INPUT) so that the receiver audio stages can be used to provide an audio output when the radio is equipped with the Intercom option.

Pin 2 is connected to the system board through P904-6 (SQ DISABLE) so that the receiver audio stages can be independently activated and used to provide an alert tone output when the radio is equipped with the Carrier controller Timer option.

SQUELCH IC

The hybrid squelch IC (U6O3) also uses a custom flip-chip monolithic integrated circuit. The squelch IC contains the noise amplifier, active noise filter, detector, slow and fast squelch circuits as well as the receiver unsquelched sensor (RUS) switch and carrier activity sensor (CAS) switch.

Noise Amp. Filter & Active Detector

Noise from the limiter/detector is coupled through the SQUELCH control to pins 1 and 2 on the squelch IC. This signal is applied to the noise amplifier and then to the active filter circuit.

The noise amp and active filter provide the gain and selectivity to distinguish between noise and audio. The filter output drives the active detector circuit to provide the squelch switching functions. Thermistor RT601 keeps the input to the active detector constant over wide variations in temperature.

Slow and Fast Squelch

With a signal below the 20 dB quieting level, the slow squelch circuit provides a conventional

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slow (200 millisecond) squelch operation to prevent rapid squelch opening and closing in weak signal areas.

A signal at or above the 20 dB quieting level is sensed by the signal level detector and activates the fast squelch circuit, providing a fast (10 millisecond) squelch operation.

The squelch circuits have two outputs. One output control the squelch switch and the other output controls the CAS switch.

NOTE

In Station applications, the Fast Squelch function is disabled by removing C630.

Squelch Switch

The squelch switch output at pin 7 is connected to pin 1 of the audio IC. When the receiver is squelched, the output pin at 7 is near A-. This keeps the receiver audio stages turned off, muting the receiver. When the receiver is quieted by an on-frequency signal (unsquelches), the voltage at pin 7 rises to approximately +10 Volts. This turns on the audio stages and sound is heard at the speaker.

With the receiver unsquelched, the output of the squelch switch turns on the RUS switch. The output of the RUS switch is connected to the noise amplifier, providing a hysteresis loop in the squelch circuit. The RUS output increases the gain of the noise amplifier, preventing squelch closing on weak signals. The RUS output at pin 8 is also connected to the system board through R904-8 for special applications.

NOTE

In radios equipped with Channel Guard, the RUS switch will operate only when an "on-frequency" signal with the correct Channel Guard tone is applied to the receiver.

CAS Switch

The squelch circuits also drive the CAS switch. When the receiver unsquelches, the voltage at pin 6 rises to approximately 10 volts. This voltage is connected to the system board through P904-9, and is used to turn on an optional Channel Busy light on the control unit.

NOTE

The CAS switch will operate whenever an "on-frequency" signal is received, with or without a correct Channel Guard tone.

VOICE GUARD APPLICATIONS

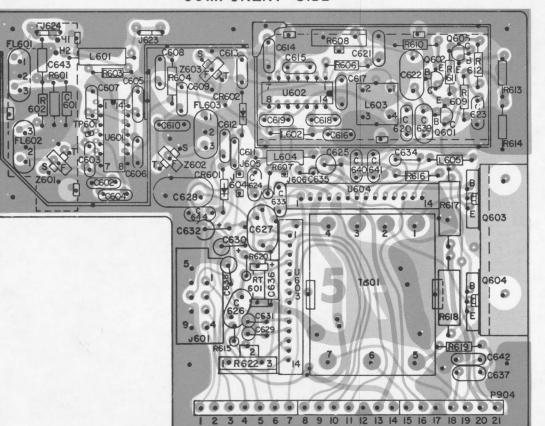
To incorporate the Voice Guard digital speech encryption option, certain minor modifications must be made. The Modification Instructions are provided along with supporting diagrams.



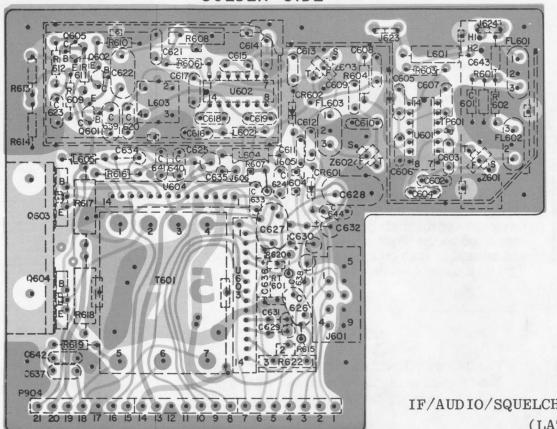
GE Mobile Communications

IF/AUDIO/SQUELCH BOARD 19D417707G1 & G2 (EARLY MODELS)

COMPONENT SIDE



SOLDER SIDE



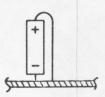
(19D423789, Sh. 2, Rev. 7)

IF/AUDIO/SQUELCH BOARD 19D432667G1 & G2 (LATER MODELS)

LEAD IDENTIFICATION

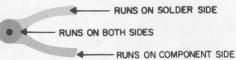
IN-LINE TRIANGULAR VIEW FROM CASE END

NOTE: LEAD ARRANGEMENT AND NOT CASE SHAPE. IS DETERMINING FACTOR FOR LEAD IDENTIFICATION. TAB INDICATES EMITTER LEAD.



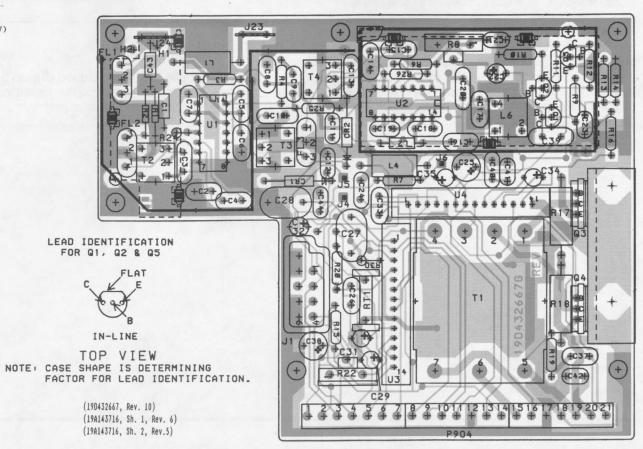
POLARITY FOR C634,C635,C630, C632,C625,C638, C631 & C629

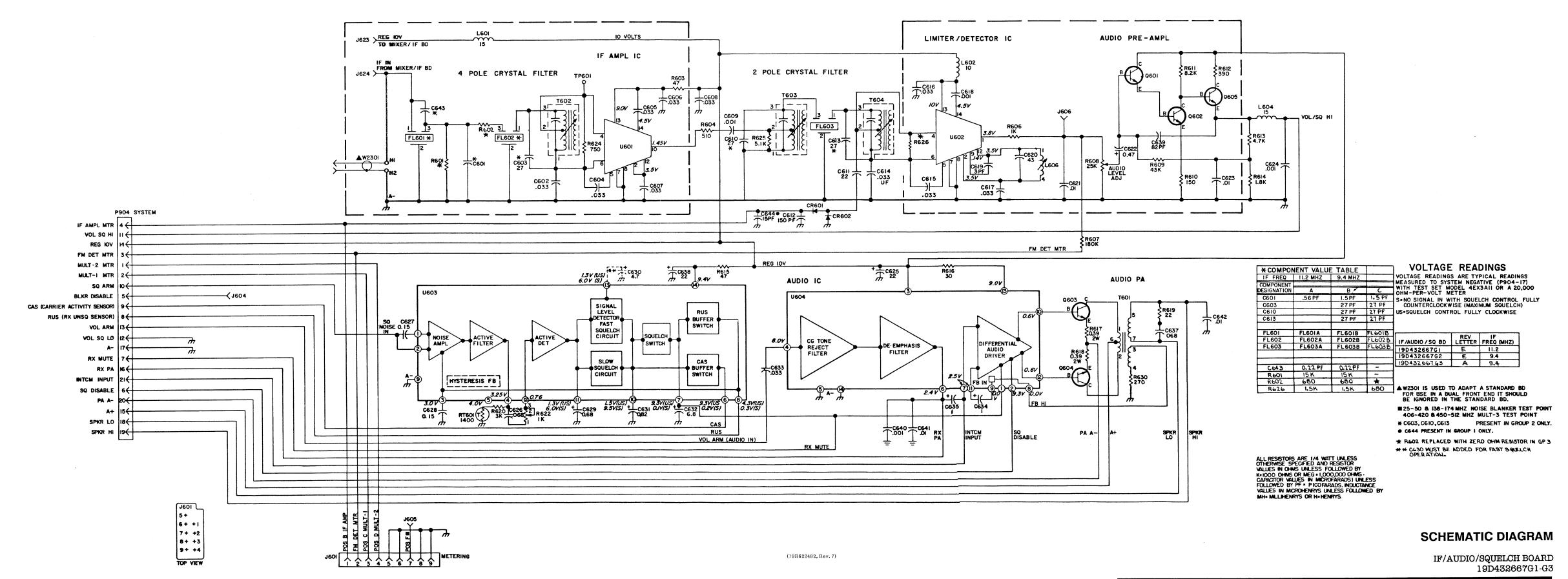
(19D423600, Rev. 8)



OUTLINE DIAGRAMS

IF/AUDIO/SQUELCH BOARDS





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PARTS LIST

IF/AUDIO/SQUELCH BOARD
19D432667G1 11.2 MHZ IF/AUDIO SQUELCH (A)
19D432667G2 9.4 MHZ IF/AUDIO SQUELCH (B)
19D432667G3 9.4 MHZ (BOU MHZ NPSPAC IF) (C)
15SUE 5

C601A 19A700013P10 Phenolic: 0.56 pF + or - 5%, 500 VDCW. (Used with 02). C601B 19A700013P15 Phenolic: 1.50 pF + or - 5%, 500 VDCW. (Used with 02 & 63). C602 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. (C604 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C606 T64 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C607 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C608 Polyester: .033 uF + or -10%, 50 VDCW. C609 T9A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RWC Type JF Discap. C610 T9A701624P118 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -30. (Used with 02 & 63). C611 T9A701624P118 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -30. (Used with 02 & 63). C612 T9A701624P18 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -30. (Used with 02 & 63). C613 T9A701624P18 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -30. (Used with 02 & 63). C614 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C617 T9A701624P201 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -30. (Used with 02 & 63). C620 T9A701624P201 Ceramic, disc: 3.0 pF + or -0.5 pF, 500 VDCW, temp coef N80 PFN + or -10%, 50 VDCW. C620 T9A701624P201 Ceramic, disc: 43 pF + or -5%, 500 VDCW, temp coef N80 PFN + or -10%, 50 VDCW. C621 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C622 T9A701534P3 Tantalum: 0.47 UF + or -10%, 50 VDCW. C623 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C624 T9A701604P19 Ceramic: 1000 pF + or -20%, 16 VDCW. C625 T9A701534P8 Tantalum: 22 uF + or -20%, 15 VDCW. C626 T644ACP310K Polyester: .068 uF + or -10%, 50 VDCW. C631 T9A143466P18 Tantalum: 22 uF + or -20%, 35 VDCW. C632 T9A143466P18 Tantalum: 22 uF + or -20%, 35 VDCW. C633 T64ACP333K Polyester: .068 uF + or -10%, 50 VDCW. C634 T9A701534P8 Tantalum: 1 uF + or -20%, 35 VDCW. C639 T9A701534P8 Tantalum: 22 uF + or -20%, 100 VDCW; sim to RMC Type JF Discap. C640 T9A701624P12 Ceramic 1000 pF + or -20%, 100 VDCW; sim to RMC Type JF Discap.	SYMBOL	GE PART NO.	DESCRIPTION
19A700013P10 Phenolic: 0.56 pF + or - 5%, 500 VDCW. (Uned with G1).			
C601B	C601A	19A700013P10	Phenolic: 0.56 pF + or - 5%, 500 VDCW.
T644ACP333K	C601B	19A700013P15	Phenolic: 1.50 pF + or - 5%, 500 VDCW.
Coef N80 PPM + or -30. (Used with 62 & G3).	C602	T644ACP333K	· ·
C609 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C610 19A701624P118 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3). C611 19A701624P516 Ceramic, disc: 22 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -60. C612 19A701602P7 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3). C613 19A701602P7 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3). C614 T644ACP333K Polyester: .033 uF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3). C618 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C619 19A701624P223 Ceramic, disc: 3.0 pF + or -5%, 500 VDCW, temp coef N150 PPM + or -120. C620 19A701624P223 Ceramic, disc: 3.0 pF + or -5%, 500 VDCW, temp coef N150 PPM + or -120. C621 T644ACP310K Polyester: .010 UF + or -10%, 50 VDCW. C622 19A701534P3 Polyester: .010 UF + or -10%, 50 VDCW. C623 T644ACP310K Polyester: .010 UF + or -10%, 50 VDCW. C624 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 UF + or -20%, 16 VDCW. C626 T644ACP368K Polyester: .016 UF + or -10%, 50 VDCW. C627 19A116080P108 Polyester: .015 UF + or -10%, 50 VDCW. C630 19A143486P18 Tantalum: 0.68 UF + or -20%, 35 VDCW. C631 19A143486P19 Tantalum: 0.68 UF + or -20%, 35 VDCW. C632 19A143486P19 Tantalum: 0.82 UF + or -10%, 50 VDCW. C633 T644ACP333K Polyester: .033 UF + or -10%, 50 VDCW. C634 19A701534P4 Tantalum: 1 UF + or -20%, 35 VDCW. C637 T644ACP368K Polyester: .068 UF + or -20%, 35 VDCW. C638 19A701534P8 Tantalum: 22 UF + or -20%, 16 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or -20%, 16 VDCW. C641 T644ACP310K Polyester: .010 UF + or -10%, 50 VDCW. C641 T644ACP310K Polyester: .010 UF + or -10%, 50 VDCW. C643 19A701624P12 Ceramic: 1000 PF + or -5%, 500 VDCW. C644 19A701624P12 Ceramic: 1000 PF + or -5%	C603	19A701624P118	Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3).
Cenamic: 1000 pF + or - 20%, 1000 VDCW; sim to RNC Type JF Discap. Cenamic: 27 pF + or -5%, 500 VDCW, temp coof N80 PPM + or -30. (Used with G2 % G3). Cenamic: 31 coof N80 PPM + or -30. (Used with G2 % G3). Cenamic: 150 pF + or -5%, 500 VDCW, temp coof N80 PPM + or -30. (Used with G2 % G3). Cenamic: 150 pF + or -20%, 1000 VDCW. Cenamic: 150 pF + or -10%, 50 VDCW. Cenamic: 1000 pF + or -10%, 50 VDCW. Cenamic: 1000 pF + or -20%, 1000 VDCW; sim to RNC Type JF Discap. Cenamic: 150 pF + or -20%, 1000 VDCW; sim to RNC Type JF Discap. Cenamic: 1000 pF + or -20%, 1000 VDCW; sim to RNC Type JF Discap. Cenamic: 1010 UF + or -10%, 50 VDCW. Cenamic: 1010 UF + or -20%, 16 VDCW. Cenamic: 1010 UF + or -20%, 16 VDCW. Cenamic: 1010 UF + or -20%, 16 VDCW. Cenamic: 1010 UF + or -10%, 50 VDCW. Cenamic: 1010 UF + or -20%, 35 VDCW. Cenamic: 1010 UF + or -20%	thru	т644АСРЗЗЗК	Polyester: .033 uF + or -10%, 50 VDCW.
C611 19A701624P516 Ceramic, disc: 22 pF + or -5%, 500 VDCW, temp coef N470 PPM + or -60. C612 19A701602P7 Ceramic: 150 pF + or -20%, 1000 VDCW. C613 19A701624P118 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 % G3). C614 thru c617 T644ACP333K Folyester: .033 uF + or -10%, 50 VDCW. C618		19A701602P19	Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
C612 19A701602P7 C613 19A70162P718 Ceramic: 150 pF + or -20%, 1000 VDCW. C614 19A70162P118 Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3). C614 thru C617 C618 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C619 19A70162P101 Ceramic, disc: 3.0 pF + or -0.5 pF, 500 VDCW, temp coef N150 PPM + or -120. C620 19A70162P123 Ceramic, disc: 3.0 pF + or -5%, 500 VDCW, temp coef N150 PPM + or -120. C621 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C622 19A701534P3 Tantalum: 0.47 uF + or -20%, 35 VDCW. C623 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C624 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C626 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C627 19A116080P108 Polyester: .0155 uF + or -10%, 50 VDCW. C628 C629 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C631 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C632 19A143486P18 Tantalum: 0.68 uF + or -10%, 50 VDCW. C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 19A701534P4 Tantalum: 1 uF + or -20%, 35 VDCW. C637 T644ACP368K Polyester: .033 uF + or -10%, 50 VDCW. C638 19A701534P8 Tantalum: 2 uF + or -20%, 35 VDCW. C639 19A10534P8 Tantalum: 2 uF + or -20%, 35 VDCW. C639 19A701534P8 Tantalum: 2 uF + or -20%, 35 VDCW. C639 19A701534P8 Tantalum: 2 uF + or -20%, 16 VDCW. C630 19A70105P32 Mics: 82 pF + or -5%, 500 VDCW. C641 19A701602P19 Polyester: .010 uF + or -10%, 50 VDCW. C642 Tormic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C643 19A70013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C644 19A70162P12 Ceramic: disc: 15 pF + or -5%, 500 VDCW.	C610	19A701624P118	Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3).
C613	C611	19A701624P516	Ceramic, disc: 22 pF + or -5%, 500 VDCW, temp coef N470 PPM + or -60.
C614 thru c617 C618	C612	19A701602P7	Ceramic: 150 pF + or -20%, 1000 VDCW.
thru c617 C618 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C619 19A701624P201 Ceramic, disc: 3.0 pF + or -0.5 pF, 500 VDCW, temp coef N150 PPM + or -120. C620 19A701624P223 Ceramic, disc: 43 pF + or -5%, 500 VDCW, temp coef N150 PPM + or -120. C621 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C622 19A701534P3 Tantalum: 0.47 uF + or - 20%, 35 VDCW. C624 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C626 C627 19A116080P108 And C628 C629 19A143486P18 Tantalum: 0.68 uF + or -10%, 50 VDCW. C631 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C632 C634 19A143486P19 Tantalum: 0.82 uF + or -10%, 35 VDCW. C635 C637 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 22 uF + or -10%, 50 VDCW. C638 19A701534P8 Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 2 uF + or -10%, 50 VDCW. C639 19A701054P8 Tantalum: 2 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. C639 19A701054P8 Tantalum: 2 uF + or -20%, 35 VDCW. Tantalum: 2 uF + or -10%, 50 VDCW. C639 19A701054P8 Tantalum: 2 uF + or -20%, 16 VDCW. C640 19A70105P19 Ceramic: 1000 pF + or -20%, 16 VDCW. CMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C640 19A70103P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C986 C644 19A70104P12 Ceramic disc: 15 pF + or -5%, 500 VDCW. temp	C613	19A7Ö1624P118	Ceramic, disc: 27 pF + or -5%, 500 VDCW, temp coef N80 PPM + or -30. (Used with G2 & G3).
C618	thru	T644ACP333K	
C619		19A701602P19	
C620	C619	19A701624P201	
Tantalum: 0.47 uF + or - 20%, 35 VDCW. C623 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C624 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C626 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C627 19A116080P108 Polyester: .0155 uF + or -10%, 50 VDCW. C628 Tantalum: 0.68 uF + or -20%, 35 VDCW. C629 19A143486P18 Tantalum: 0.82 uF + or -10%, 35 VDCW. C631 19A143486P19 Tantalum: 0.82 uF + or -10%, 35 VDCW. C632 19A143486P21 Tantalum: 6.8 uF + or -20%, 35 VDCW. C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 19A701534P4 Tantalum: 1 uF + or -20%, 35 VDCW. C635 T644ACP368K Polyester: .068 uF + or -20%, 35 VDCW. C638 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 T9A701624P12 Phenolic: 0.22 pF + or -5%, 500 VDCW. C644 19A701624P12 Phenolic: 0.22 pF + or -5%, 500 VDCW.	C620	19A701624P223	Ceramic, disc: 43 pF + or -5%, 500 VDCW, temp
C623 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C624 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C626 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C627 19A116080P108 Polyester: 0.155 uF + or -10%, 50 VDCW. C628 Tantalum: 0.68 uF + or -20%, 35 VDCW. C631 19A143486P18 Tantalum: 0.82 uF + or -20%, 35 VDCW. C632 19A143486P21 Tantalum: 6.8 uF + or -20%, 35 VDCW. C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 19A701534P4 Tantalum: 1 uF + or -20%, 35 VDCW. C635 T644ACP368K Polyester: .068 uF + or -20%, 35 VDCW. C636 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or -20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 19A70013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C644 19A701624P12 Ceramic. 15 pF + or -5%, 500 VDCW.	C621	T644ACP310K	Polyester: .010 uF + or -10%, 50 VDCW.
C624 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C625 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C626 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C627 19A116080P108 and C628 C629 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C631 19A143486P19 Tantalum: 0.62 uF + or -10%, 50 VDCW. C632 19A143486P19 Tantalum: 0.82 uF + or -10%, 35 VDCW. C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 and C635 C637 T644ACP334P4 Tantalum: 1 uF + or -20%, 35 VDCW. C638 19A701534P4 Tantalum: 22 uF + or -10%, 50 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C643 19A70013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C644 19A701624P12 Ceramic, 150 FF + or -5%, 500 VDCW. temp	C622	19A701534P3	Tantalum: 0.47 uF + or - 20%, 35 VDCW.
RMC Type JF Discap. Tantalum: 22 uF + or -20%, 16 VDCW. Polyester: .068 uF + or -10%, 50 VDCW. 19A116080P108 and c628 Tantalum: 0.68 uF + or -10%, 50 VDCW. Polyester: 0.155 uF + or -10%, 50 VDCW. Tantalum: 0.68 uF + or -20%, 35 VDCW. Tantalum: 0.82 uF + or -10%, 35 VDCW. Tantalum: 6.8 uF + or -20%, 35 VDCW. Tantalum: 6.8 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 1 uF + or -20%, 35 VDCW. Tantalum: 2 uF + or -10%, 50 VDCW. Tantalum: 2 uF + or -20%, 16 VDCW. Tantalum: 22 uF + or -5%, 500 VDCW.	C623	T644ACP310K	Polyester: .010 uF + or -10%, 50 VDCW.
C626 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C627 and c628 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C629 19A143486P18 Tantalum: 0.68 uF + or -20%, 35 VDCW. C631 19A143486P19 Tantalum: 0.82 uF + or -10%, 35 VDCW. C632 19A143486P21 Tantalum: 6.8 uF + or -20%, 35 VDCW. C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 and c635 19A701534P4 Tantalum: 1 uF + or -20%, 35 VDCW. C636 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C638 19A701534P8 Tantalum: 2 uF + or -20%, 16 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Mica: 82 pF + or -5%, 500 VDCW. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 19A70013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C643 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW.	C624	19A701602P19	Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
Tantalum: 0.68 uF + or -10%, 50 VDCW.	C625	19A701534P8	Tantalum: 22 uF + or -20%, 16 VDCW.
and C628 C629 C629 C629 C631 C631 C631 C631 C631 C632 C631 C632 C632 C632 C633 C633 C633 C634 C634 C635 C637 C636 C637 C637 C638 C637 C638 C638 C639 C639 C639 C639 C639 C639 C639 C639	C626	T644ACP368K	Polyester: .068 uF + or -10%, 50 VDCW.
Tantalum: 0.82 uF + or -10%, 35 VDCW. 19A143486P119 Tantalum: 6.8 uF + or -20%, 35 VDCW. 2633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. 2634 Tantalum: 1 uF + or -20%, 35 VDCW. 2637 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. 2638 T9A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. 2639 T9A700105P32 Mica: 82 pF + or -5%, 500 VDCW. 2640 T9A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. 2641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. 2642 C643 T9A700013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. 2644 T9A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW. temp	and	19A116080P108	Polyester: 0.155 uF + or -10%, 50 VDCW.
C632	C629	19A143486P18	Tantalum: 0.68 uF + or -20%, 35 VDCW.
C633 T644ACP333K Polyester: .033 uF + or -10%, 50 VDCW. C634 and c635 C637 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C638 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 (0542 UP + or -10%, 50 VDCW. C643 19A700013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	C631	19A143486P119	Tantalum: 0.82 uF + or ~10%, 35 VDCW.
C634 and c635 C637 C637 C638 C638 C639 C639 C639 C639 C639 C639 C640 C640 C640 C641 C641 C641 C641 C641 C642 C643 C643 C644 C643 C644 C64	C632	19A143486P21	Tantalum: 6.8 uF + or -20%, 35 VDCW.
and C635 C637 C638 T644ACP368K Polyester: .068 uF + or -10%, 50 VDCW. C638 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C639 19A70105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 and C642 C643 19A700013P5 Phenolic: 0.22 pF + or -5%, 500 VDCW. (Used with G1 & G2). C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	C633	T644ACP333K	Polyester: .033 uF + or -10%, 50 VDCW.
C638 19A701534P8 Tantalum: 22 uF + or -20%, 16 VDCW. C639 19A700105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 C643 19A700013P5 Phenolic: 0.22 pF + or - 5%, 500 VDCW. C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	and	19A701534P4	Tantalum: 1 uF + or - 20%, 35 VDCW.
C639 19A700105P32 Mica: 82 pF + or -5%, 500 VDCW. C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 T644ACP310K Polyester: .010 uF + or -10%, 50 VDCW. C642 C643 19A700013P5 Phenolic: 0.22 pF + or - 5%, 500 VDCW. (Used with G1 & G2). C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	C637	T644ACP368K	Polyester: .068 uF + or -10%, 50 VDCW.
C640 19A701602P19 Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C641 and c642 Polyester: .010 uF + or -10%, 50 VDCW. C643 19A700013P5 Phenolic: 0.22 pF + or - 5%, 500 VDCW. (Used with G1 & G2). C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	C638	19A701534P8	Tantalum: 22 uF + or -20%, 16 VDCW.
RMC Type JF Discap. C641 and C642 C643 19A700013P5 Phenolic: 0.22 pF + or - 5%, 500 VDCW. (Used with Gl & G2). C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	C639	19A700105P32	Mica: 82 pF + or -5%, 500 VDCW.
and C642	C640	19A701602P19	Ceramic: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
(Used with Gl & G2). C644 19A701624P12 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp	and	T644ACP310K	Polyester: .010 uF + or -10%, 50 VDCW.
C644 19A701624Pl2 Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp coef 0 PPM + or -30. (Used with G1).	C643	19A700013P5	Phenolic: 0.22 pF + or - 5%, 500 VDCW. (Used with G1 & G2).
	C644	19A701624P12	Ceramic, disc: 15 pF + or -5%, 500 VDCW, temp

SYMBOL	GE PART NO.	DESCRIPTION
		RECTIFIERS
CR601 and CR602	4038056P1	Germanium, fast recovery, 20 reverse volts, fwd current 40 mA.
FL601A	19B219573G3	Crystal: Resonator A - 11,200.000; Resonator B - 11,196.024 kHz (Quantity 2 - Used with G1).
FL601B	19B219574G3	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9396.024 kHz (Quantity 2 - Used with G2 & G3).
FL602A		Part of FL601A. (Used with G1).
FL602B		Part of FL601B. (Used with G2 & G3).
FL603A	19B219573G6	Crystal: Resonator A - 11,200.000; Resonator B - 11,200.000 kHz. (Used with G1).
FL603B	19B219574G1	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9400.000 kHz. (Used with G2 & G3).
J601	19B219374G1	Connector. Includes:
	19C317957P1	Shell.
	19A700237P1	Contact, electrical.
J604 thru J606	19A701785P1	Contact, electrical; sim to Molex 08-50-0404.
J623 and J624	19Al16975Pl	Contact, electrical.
1601	10.700000000	INDUCTORS
L601	19A700000P25	Coil, RF: 15 uH + or -10%; sim to Jeffers 4421-9K.
L602	19A700024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res max.
L604	19A700000P25	Coil, RF: 15 uH + or -10%; sim to Jeffers 4421-9K.
L606A	19C311181G13	Coil. Includes: Tuning slug. (Used with G1).
L606B	19C311181G14	Coil. Includes: Tuning slug. (Used with G2 & G3).
P904	19B219594P1	Contact, electrical: 7 pins.
Q601 and Q602	19A700023P1	Silicon, NPN; sim to Type 2N3904.
Q603 and Q604		Part of Heat Sink (19B226657G1).
Q605	19A700023P1	Silicon, NPN; sim to Type 2N3904.
R601	3R151P153J	Composition: 15K ohms + or - 5%, 1/8 w. (Used with G1 & G2).
R601	19A700184P1	Jumper. (Used with G3).
R602	3R151P681J	Composition: 680 ohms + or - 5%, 1/8 w.
R603	H212CRP047C	Deposited carbon: 47 ohms + or -5%, 1/4 w.
R604	19A143400P33	Deposited carbon: 510 ohms + or - 5%, 250 VDCW, 1/4 w.
R606	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.
R607	H212CRP418C	Deposited carbon: 0.18M ohms + or -5%, 1/4 w.
R608	19B209358P107	Variable, carbon film: approx 800 to 25K ohms + or - 10%, 1/4 w; sim to CTS Type X-201.
R609	19A143400P56	Deposited carbon: 43K ohms + or - 5%, 250 VDCW, 1/4 w.
	H212CRP115C	Deposited carbon: 150 ohms + or -5%, 1/4 w.
R610		
R610 R611	H212CRP282C	Deposited carbon: 8.2K ohms + or -5%, 1/4 w.

SYMBOL	GE PART NO.	DESCRIPTION		SYMBOL	GE PART NO.	DESCRIPTION
		RECTIFIERS	1	R613	H212CRP247C	Deposited carbon: 4.7K ohms + or -5%, 1/4 w.
CR601	4038056P1	Germanium, fast recovery, 20 reverse volts, fwd		R614	H212CRP218C	Deposited carbon: 1.8K ohms + or -5%, 1/4 w.
and CR602		current 40 mA.		R615	H212CRP047C	Deposited carbon: 47 ohms + or -5%, 1/4 w.
				R616	19A143400P18	Deposited carbon: 30 ohms + or - 5%, 250 VDCW, 1/4 w.
FL601A	19B219573G3	Crystal: Resonator A - 11,200.000; Resonator B - 11,196.024 kHz (Quantity 2 - Used with G1).		R617 and	19B209022P5	Wirewound: 0.39 ohms + or -5%, 2 w; sim to IRC Type BWH
FL601B	19B219574G3	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9396.024 kHz (Quantity 2 - Used with G2 & G3).		R618 R619	H212CRP022C	Deposited carbon: 22 ohms + or -5%, 1/4 w.
FL602A		Part of FL601A. (Used with G1).		R620	19A143400P42	Deposited carbon: 3K ohms + or - 5%, 250 VDCW, $1/4\ w$.
FL602B FL603A	19B219573G6	Part of FL601B. (Used with G2 & G3). Crystal: Resonator A - 11,200.000; Resonator B		R622	19B209358P103	Variable, carbon film: approx 50 to 1K ohms + or -10%, 0.2 w; sim to CTS Type X-201.
		- 11,200.000 kHz. (Used with G1).		R624	19A143400P35	Deposited carbon: 750 ohms + or - 5%, 1/4 w.
FL603B	19B219574G1	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9400.000 kHz. (Used with G2 & G3).		R625	19A143400P45	Deposited carbon: 5.1K ohms + or -5%, 250 VDCW 1/4 w.
			1	R626	H212CRP215C	Deposited carbon: 1.5K ohms + or -5%, 1/4 w.
J601	19B219374G1	Connector. Includes:	1	R626	H212CRP168C	Deposited carbon: 680 ohms + or -5%, 1/4 w.
	19C317957P1	Shell.	1	R630	H212CRP127C	Deposited carbon: 270 ohms + or -5%, 1/4 w.
	19A700237P1	Contact, electrical.				
J604 thru J606	19A701785P1	Contact, electrical; sim to Molex 08-50-0404.		RT601	5490828P38	Thermistor: 1400 ohms + or -5%, color code green and white; sim to Carborundum Type 723H-2
J623 and	19A116975P1	Contact, electrical.				
J624				T601	19A701978P1	Audio Freq: Pri: 12 ohms + or -5%, Sec (1): 10 ohms + or -5%, Sec (2): 8 ohms + or -5%.
L601	19A700000P25	Coll DR. 15 W. Land 100 and the Turner		T602 thru	19A134747P2	Transformer, IF: resonant freq. 10.7 MHz; sim toko Inc. 154 PC-470073N3.
L602	19A700004P25	Coil, RF: 15 uH + or -10%; sim to Jeffers 4421-9K.		T604		
1602	194/00024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res max.				
L604	19A700000P25	Coil, RF: 15 uH + or -10%; sim to Jeffers 4421-9K.		TP601	N503P304F15	Cotter pin.
L606A	19C311181G13	Coil. Includes: Tuning slug. (Used with G1).	$ \cdot $	U601	19A116445P1	INTEGRATED CIRCUITS
L606B	19C311181G14	Coil. Includes: Tuning slug. (Used with G2 & G3).		and U602		Integrated circuit, linear: sim to ULN2111.
			Н	U603	19D416560G3	Hybrid Squelch.
P904	19B219594P1	Contact, electrical: 7 pins.		U604	19D437565G1	Hybrid, audio.
						MISCELLANEOUS
Q601 and	19A700023P1	Silicon, NPN; sim to Type 2N3904.			19B226657G1	Heat sink. (Includes Q603 & Q604).
Q602 Q603		Part of Heat Sink (19B226657G1).	П		19B226648G1 19B219571G1	Shield. (Located by FL601, PL602). Shield. (Located on opposite side of printed board from R601, R602).
and Q604			П		19B219554G1	Can. (Located around U602).
Q605	19A700023P1	Silicon, NPN; sim to Type 2N3904.	П		19B219555Pl	Cover. (Used with can).
					19B219727G1	Shield. (Located under can).
R601	3R151P153J	Composition: 15K ohms + or - 5%, 1/8 w. (Used with Gl & G2).			19A701883P4	Contact, electrical; sim to AMP 86444-1.
R601	19A700184P1	Jumper. (Used with G3).	П			
R602	3R151P681J	Composition: 680 ohms + or - 5%, 1/8 w.	П			
R603	H212CRP047C	Deposited carbon: 47 ohms + or -5%, 1/4 w.	П			
R604	19A143400P33	Deposited carbon: 510 ohms + or - 5%, 250 VDCW, 1/4 w.	П			
R606	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.	Ш			
R607	H212CRP418C	Deposited carbon: 0.18M ohms + or -5%, 1/4 w.	П			
R608 R609	19B209358P107	Variable, carbon film: approx 800 to 25K ohms + or - 10%, 1/4 w; sim to CTS Type X-201.				
кооч	19A143400P56	Deposited carbon: 43K ohms + or - 5%, 250 VDCW, 1/4 w.	П			
R610	H212CRP115C	Deposited carbon: 150 ohms + or -5%, 1/4 w.				
R611	H212CRP282C	Deposited carbon: 8.2K ohms + or -5%, 1/4 w.				
R612	H212CRP139C	Deposited carbon: 390 ohms + or -5%, 1/4 w.	$\ \ $			
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*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

PARTS LIST

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circlust are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all pervious revisions. Refer to the Parts List for the descriptions of parts affected by these revisions.

REV. A - IFAS BOARD 19D432667G1,2
To improve receiver two signal selectivity, deleted L605. L605 was 19A700000P25 - Coil, RF, 15.0 uF \pm 10%.

REV. B - IFAS BOARD 19D432667G1,2

To prevent audio instabilities with non-standard speaker loading, deleted C636. Changed C634 and C635.

C634 and C635 were 19A143486P115 - Tantalum: .22 uF \pm 10%, 35 VDCW.

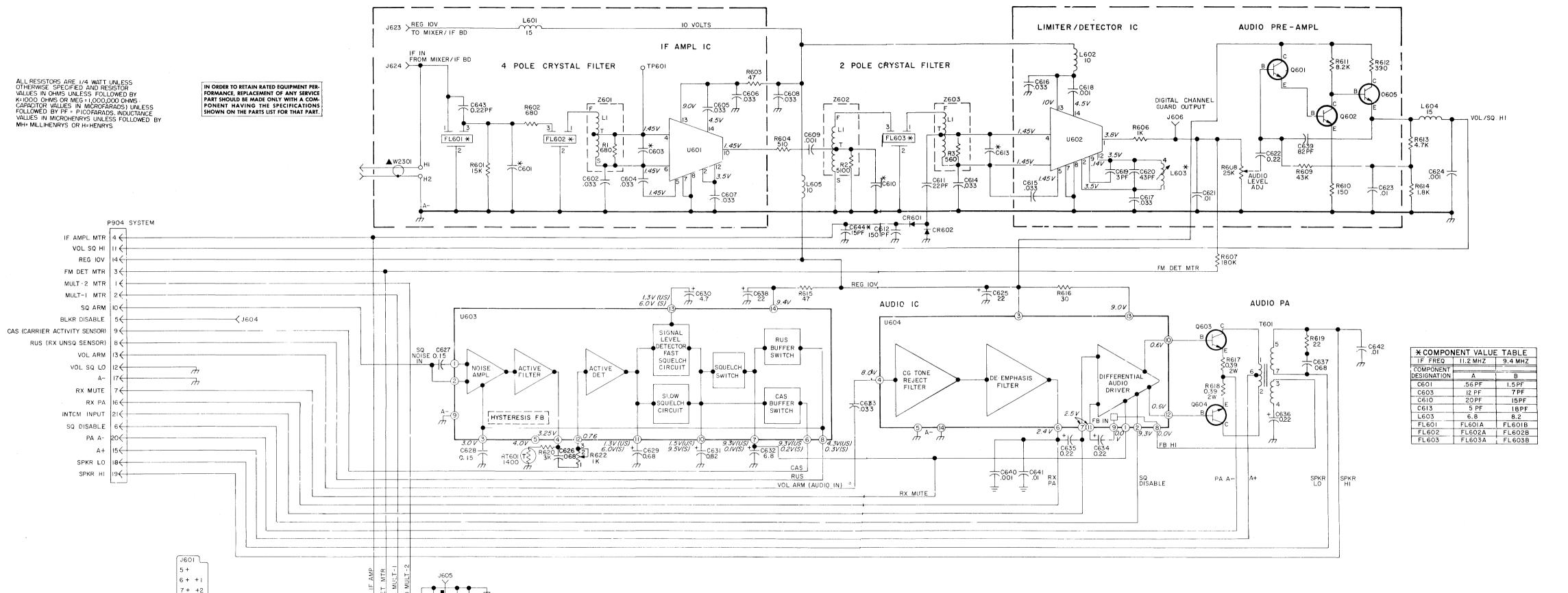
REV. C - IFAS BOARD 19D432667G1,2

To prevent audio power spec. Replaced DA wire jumper (H4 to H3) with a 270-ohm resistor (R630).

REV. D - $\frac{1}{1}$ IFAS BOARD $\frac{190432667G1}{2}$ To disable the fast squelch function, deleted C630.

C630 was 19A701534P6 - Tantalum: 4.7 uF +20%, 35 VDCW.

REV. E - IFAS BOARD 19D432667G1,2
REV. A - IFAS BOARD 19D432667G3
To improve adjacent channel selectivity. Altered Printed wire Board 19D432668P1 to seperate input and output across IF filters PL601/FL602.



(19R622135, Rev. 16)

8+ +3

9+ +4 TOP VIEW **VOLTAGE READINGS**

VOLTAGE READINGS ARE TYPICAL READINGS MEASURED TO SYSTEM NEGATIVE (P904-17) WITH TEST SET MODEL 4EX3AII OR A 20,000 OHM-PER-VOLT METER

S=NO SIGNAL IN WITH SQUELCH CONTROL FULLY COUNTERCLOCKWISE (MAXIMUM SQUELCH) US=SQUELCH CONTROL FULLY CLOCKWISE

IF/AUDIO/SQ BD	LETTER	F FREQ (MHZ)
19D417707G1	К	11.2
19D417707G2	к	9.4

- ▲ W2301 IS USED TO ADAPT A STANDARD BD FOR USE IN A DUAL FRONT END IT SHOULD BE IGNORED IN THE STANDARD BD.
- ■25-50 & 138-174 MHZ NOISE BLANKER TEST POINT 406-420 & 450-512 MHZ MULT-3 TEST POINT * C644 IN GROUP I ONLY.

SCHEMATIC DIAGRAM

IF/AUDIO/SQUELCH BOARD 19D417707G1 AND G2

PARTS LIST

1F/AUDIO/SQUELCH BOARD
19D417707G1 11.2 MHz IF/AUDIO SQUELCH (A) REV K
19A417707G2 9.4 MHz IF/AUDIO SQUELCH (B) REV K

SYMBOL	GE PART NO.	DESCRIPTION
C601A	19A700013P10	Phenolic: 0.56 pf ±5%, 500 VDCW.
C601B	19A700013P15	Phenolic: 1.5 pf ±5%, 500 VDCW.
C602	19A700005P10	Polyester: 0.033 µf ±10%, 50 VDCW.
C603A	5496219P642	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -470 PPM.
C603B*	5496219P638	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM.
	5496219P647	In REV E & earlier: Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -470 PPM.
C604 thru C608	19A700005P10	Polyester: 0.033 µf ±10%, 50 VDCW.
C609	5494481P111	Ceramic disc; 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C610A	5496219P646	Ceramic disc: 20 pf ±5%, 500 VDCW, temp coef -470 PPM.
C610B*	5496219P644	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -470 PPM.
		In REV E & earlier;
	5496219P649	Ceramic disc: 27 pf ±5%, 500 VDCW.
C611	549621 9 P647	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef
C612	5494481P101	-470 PPM. Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C613A*	5496219P636	RMC Type JF Discap. Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM.
002011		coef -470 PPM.
		In REV B-D:
	5496219P642	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -470 PPM.
		In REV A & earlier:
	5496219P636	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM.
C613B*	5496219P645	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef -470 PPM.
		In REV E:
	5496219P649	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -470 PPM.
		In REV D & earlier;
	5496219P645	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef
C614 thru C617	19A700005P10	Polyester: 0.033 µf ±10%, 50 VDCW.
C618	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C619	19A116656P3J1	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coe-150 PPM.
C62Q	19A116656P43J1	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef -150 PPM.
C621	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCW.
C622	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.
C623	19A11608QP101	Polyester: 0.01 µf ±10%, 50 VDCW.
C624	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C625	5496267P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.
		LETED OR CHANGED BY PRODUCTION CHAN

SYMBOL	GE PART NO.	DESCRIPTION
C626	19A116080P106	Deliver of the second of the s
C627	19A116080P108	Polyester: 0.068 µf ±10%, 50 VDCW.
C628*	19A116080P108	Polyester: 0.15 \(\mu f \pm 10\% \), 50 VDCW. Polyester: 0.15 \(\mu f \pm 10\% \). 50 VDCW.
C028+	1541100807108	
	19A116080P109	In REV B & earlier:
6400		Polyester: 0.22 µf ±10%, 50 VDCW.
C629	19A134202P13	Tantalum: 0.68 μf ±20%, 35 VDCW.
C630	19A134202P3	Tantalum: 4.7 µf ±20%, 10 VDCW.
C631	5496267P230	Tantalum: 0.82 μf ±20%, 35 VDCW; sim to Sprague Type 150D.
C632	19A134202P15	Tantalum: 6.8 µf ±20%, 35 VDCW.
C633*	19A700005P10	Polyester: 0.033 µf ±10%, 50 VDCW.
		Earlier than REV A:
	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCW.
C634	19A134202P110	Tantalum: 0.22 µf ±10%, 35 VDCW.
and C635		
C636	5496267P226	Tantalum: 0.22 µf ±10%, 35 VDCW; sim to Sprague
		Type 150D.
C637	19A116080P106	Polyester: 0.068 μf ±10%, 50 VDCW.
C638	5496267P10	Tantalum: 22 μ f $\pm 20\%$, 15 VDCW; sim to Sprague Type 150D.
C639	19A700105P32	Mica: 82 pf ±5%, 500 VDCW.
C640	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW.
	19A116080P101	
C641 and	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCW.
C642		District Control of the Control of t
C643	19A700013P5	Phenolic: 0.22 pf ±5%, 500 VDCW.
C644*	19A116656P15J0	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef 0 PPM. Added to G1 by REV F.
CR601	4038056P1	DIODES AND RECTIFIERS Germanium, fast recovery, 20 Rev volts, Fwd.
and CR602	403803471	current 40 mA.
FL601A	19B219573G3	Crystal, freq: Resonator A: 11,200000 KHz,
		Resonator B: 11,196024 KHz. Resonator A: 11,200000 KHz, Resonator B: 11,196024 KHz.
FL601B	19B219574G3	Crystal, freq: Resonator A: 9400.300 KHz, Resonator B: 9396,324 KHz, Resonator A: 9400.300 KHz,
	1	Resonator B: 9396.324 KHz.
FL602A		(Part of FL601A).
FL602B	1	(Part of FL601B).
FL603A*	19B219573G6	Crystal, freq: Resonator A: 11,200000 KHz, Resonator B: 11,200000 KHz,
	1	In 19D417707G1 REV D & earlier:
	19B219573G1	Crystal, freq: Resonator A: 11,200000 KHz, Resonator B: 11,200000 KHz.
FL603B	19B219574G1	Crystal freq: Resonator A: 9400.300 KHz, Resonator B: 9400.300 KHz.
]	JACKS AND RECEPTACLES
.1601	19B219374G1	Connector. Includes:
J601		Shell.
	19C317957P1	
	19A116651P1	Contact, electrical; sim to Malco X0-2864.
J604 thru J606	19A701785P1	Contact, electrical; sim to Molex 08-50-0404.
J623 and J624	19A116975P1	Contact, electrical.
J623 and	19A116975P1	Contact, electrical.

SYMB0L	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
		INDUCTORS	U603*	19D416560G3	Squelch Hybrid.
601	19A700000P25	Coil, RF: 15.0 µh ±10%, 1.20 ohms DC res max.			In REV B & C:
				19D416560G2	Squelch Hybrid. In REV A & earlier:
602	19A700024P25	Coil, RF: 10.0 µh ±10%, 3.70 ohms DC res max.		19D416560G1	Squelch Hybrid.
.603A	19C311181G13	Coil.	U604	19D416573G1	Audio Hybrid.
603B	19C311181G14 19A700000P25	Coil. Coil, RF: 15.0 µh ±10%, 1.20 ohns DC res max.		10011001041	
.604 .605	19A700000P25	Coil, RF: 10 µh ±10%, 1.20 onus be res max.			NETWORKS
2003	158700024725	1001, M. 10 pm 220%	Z601*	19B226649G4	Coil assembly, Includes:
			R1	19A700106P59	Resistor, composition: 680 ohms ±5%, 1/4 w.
904	19B219594P1	Contact, electrical: 7 pins.			In REV E & earlier:
				19B226649G1	Coil assembly, Includes:
601	19A115910P1	Silicon, NPN; sim to Type 2N3904.	R1	3R152P681J	Resistor, composition: 680 ohms ±5%, 1/4 w.
1d 502			Z602*	19B226649G5	Coil assembly. Includes: Resistor, composition: 5100 ohms ±5%, 1/4 w.
603	19A116742P1	Silicon, NPN. (Part of heat sink assembly).	R2	3R152P512J	In REV E & earlier:
nd 604				19B226649G2	Coil assembly. Includes:
605	19A115910P1	Silicon, NPN; sim to Type 2N3904.	, no	3R152P512J	Resistor, composition: 5.1K ohms ±5%, 1/4 w.
		RESISTORS	R2 Z603*	3R152P512J	Coil assembly. Includes:
	10.50001575		R3	198226649G6 19A700106P57	Resistor, composition: 560 ohms ±5%, 1/4 w.
601	19A700019P51	Deposited Carbon: 15K ohms ±5%, 0.25 w. Deposited Carbon: 680 ohms ±5%, 0.25 w.	*3	15A TOOLOGEST	In REV E & earlier;
602	19A700019P35	Deposited Carbon: 680 onms 15%, 0.25 w. Deposited Carbon: 47 ohms ±5%, 0.25 w.		19B226649G3	Coil assembly. Includes:
603	19A700019P21	·	R3	3R152P561J	Resistor, composition: 560 ohms ±5%, 1/4 w.
604 606	19A143400P33 19A700019P37	Deposited Carbon: 510 ohms ±5%, 250 VDCW; 1/4 w. Deposited Carbon: 1K ohms ±5%, 0.25 w.			
	19A700019P37	Deposited Carbon: 180K ohms ±5%, 0.25 w.			MISCELLANEOUS
507 508	19B209358P107	Variable, carbon film: approx 800 to 25K ohms ±10%, 0.25 w; sim to CTS Type X-201.		19B226657G1	Heat sink. (Includes Q603, Q604).
9	19A143400P56	Deposited Carbon: 43K ohms ±5%, 1/4 w.		19A700068P1	Insulator, bushing. (Used with Q603, Q604).
0	19A700019P27	Deposited Carbon: 150 ohms ±5%, 0.25 w.		4029846P1	Hex nut: No. 4-40. (Used with Q603, Q604).
.1	19A700019P48	Deposited Carbon: 8.2K ohms ±5%, 1/4 w.		19A700115P3	Insulator, plate. (Used with Q603, Q604).
2	19A700019P32	Deposited Carbon: 390 ohms ±5%, 0.25 w.		N187P9006C6	Machine screw, slotted, hex/washer head: 4-40 3/8. (Secures Q603 & Q604).
3	19A700019P45	Deposited Carbon: 4.7K ohms ±5%, 0.25 w.		19B226648G1	Shield. (Located by FL601, FL602).
14	19A700019P40	Deposited Carbon: 1.8K ohms ±5%, 0.25 w.		19B219571G1	Shield. (Located on opposite side of printed
15	19A700019P21	Deposited Carbon: 47 ohms ±5%, 0.25 w.			board from R601, R602).
16	19A143400P18	Deposited Carbon: 30 ohms ±5%, 0.25 w.		19B219727G1	Shield. (Located under can).
317 id	19B209022P5	Wirewound: 0.39 ohms ±5%, 2 w; sim to IRC Type BWH.	 	19B219554G1	Can. (Located around U602).
18		, Ban.		19B219555P1	Cover. (Used with can).
19	19A700019P17	Deposited Carbon: 22 ohms ±5%, 0.25 w.		19A701883P4	Contact, electrical: sim to AMP 86444-1.
0	19A143400P42	Deposited Carbon: 3K ohms ±5%, 1/4 w.		1	
1*	19A700019P45	Deposited Carbon: 4.7% ohms ±5%, 1/4 w. Deleted b	y		
2*	19B209358P103	Variable, carbon film: approx 50 to 1K ohms ±10%, 0.2 w; sim to CTS Type X-201. Added by REV B.			
3*	3R151P204J	Composition: 200K ohms ±5%, 1/8 w. Added by REV F.			
01	5490828P38	Thermistor: 1.4K ohms ±5%, color code green and white; sim to Carborundum 723H-2.			
		TRANSFORMERS			
1	19A116747P1	Audio freq: 500 to 4000 Hz, ±0.25 dB, Pri: 12.0 ohm ±5%,			
		Audio freq: 500 to 4000 hz, 15.25 db, Pri: 12.0 ohm ±5%, Sec 1: 8.0 ohms. 15 w, Sec 2: 1.4 ±0.10 VRMS.			
		TEST POINTS			
601	N503P304F15	Cotter pin.			
		INTEGRATED CIRCUITS			•
	10111044801	Linear: sim to ULN 2111.	1	1	i .
01 d	19A116445P1	Minorit. Dim to om 22221			

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

PARTS LIST

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A To improve audio frequency response. Changed C633 and deleted R621.
- REV. B To improve operation of squelch circuit. Changed W603, added R622 and changed PWB from 19D417682 to 19D423789.
- REV. C To improve operation of squelch circuit. Changed C628.
- REV. D To improve operation of squelch circuit. Changed U603.
- REV. E 19D417707G1
 - To facilitate manufacturing. Changed C613A and FL603A.
- REV. E 19D417707G2

To improve operation. Changed C613B.

REV. F - 19D417707G2

To improve IF response. Changed C603B, C610B and C613B.

REV. F - 19D417707G1

To improve operation. Added C644.

REV. G - 19D417707G1 & G2

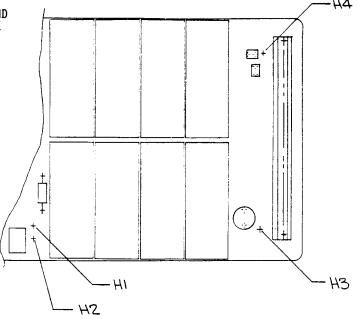
To improve performance of audio PA when using MASTR II Speaker out of housing or when a Non Standard Speaker is used, Added R623,

- REV. H To improve operation of audio PA at low voltage. Deleted R623 R623 was: 3R151P204J, composition: 200K ohms $\pm 5\%$, 1/8 W.
- REV. J Add output Jack to make compatible with Digital Channel Guard. Added J606.
- REV. K To prevent the receiver from self quieting. Added L605. (Also changed C401 on UHF Oscillator/Multiplier boards).

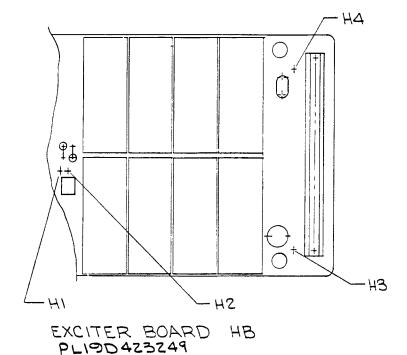
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THIS INSTRUCTION MODIFIES A HIGH BAND OR UHF MASTR II FM EXCITER FOR VOICE GUARD OPERATION.

- 1. REMOVE JUMPER BETWEN H1 & H2.
- 2. SOLDER SF24-R FROM H1 TO H3. (PL19B234774G1).
- 3. SOLDEK SF24-R FROM H2 TO H4. (PL19B234774G1)



EXCITER BOARD (UHF)
PLISD432679

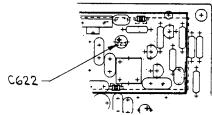




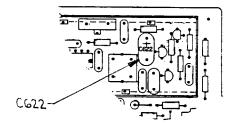
THIS INSTRUCTION MODIFIES A HIGH BAND OR UHF MASTR II RECEIVER IFAS BOARD FOR VOICE GUARD OPERATION.

- 1. REMOVE COVER FROM FM DETECTOR AREA.
- REPLACE C622(0.47 UFD) WITH A 10 UFD CAPACITOR PART NUMBER 315A6047P106N (OBSERVE CORRECT POLARITY).
- REPLACE COVER.

IF/AUDIO/SQUELCH BOARD 19D432667GI



IF/AUDIO/SQUELCH BOARD
19D417707G1

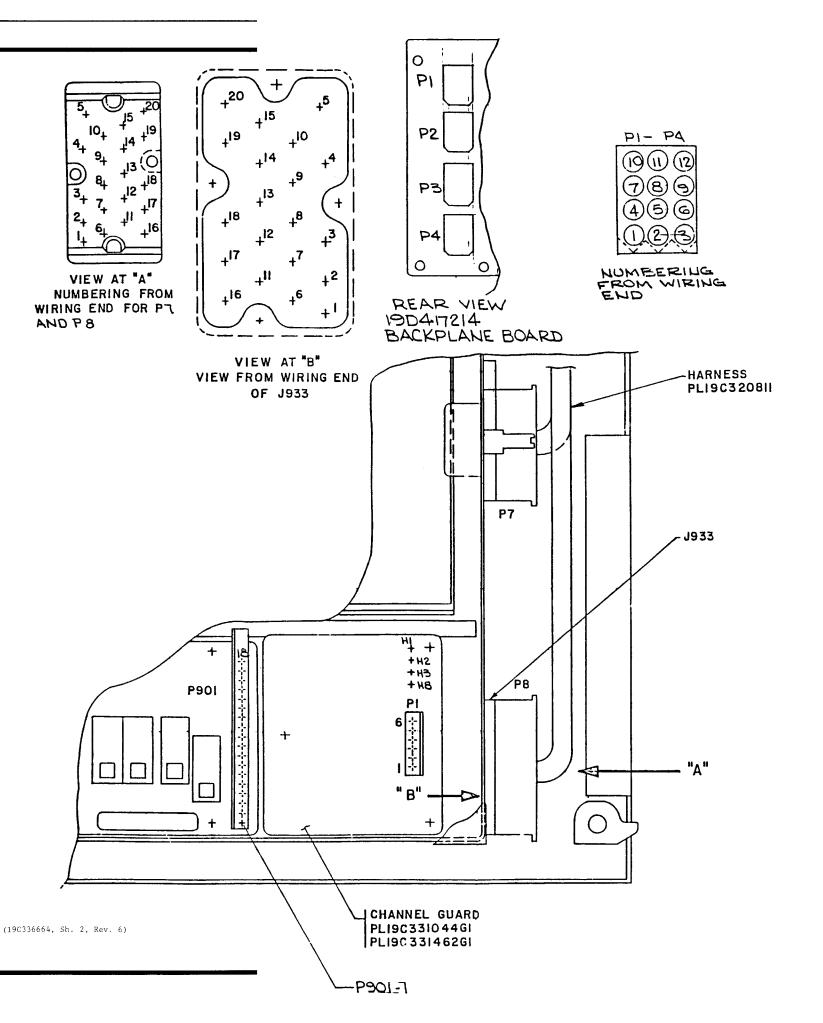


(19C336664, Sh. 1, Rev. 1)

MODIFICATIONS INSTRUCTIONS

VOICE GUARD APPLICATIONS

- THESE INSTRUCTIONS COVER THE INSTALLATION OF CABLE HARNESS PL19C851484 G2 & G3
 - 1. INSTALL DA JUMPER BETWEEN H3 & H8 ON CG ENCODER. IF H8 NOT PRESENT CUT TERMINAL FROM WRBL WIRE (PL19234774G3) AND SOLDER TO H3. CONNECT OTHER END TO J933-18 AND SPOT TIE TO EXISTING CHANNEL GUARD HARNESS. SKIP TO STEP 3 IF H8 IS NOT PRESENT.
 - IF H8 IS PRESENT, INSTALL WRBL WIRE (PL198234774G3) IN P1-2 & SOLDER OTHER END TO J933-18 & SPOT TIE TO EXISTING CHANNEL GUARD HARNESS.
 - 3. INSTALL YELLOW WIRE (PL198234774G4) IN P901-2 & SOLDER OTHER END TO J933-19 & SPOT TIE TO EXISTING EXCITER HARNESS.
 - 4. INSTALL ORANGE WIRE (PL198234774G2) IN P901-18 & SOLDER OTHER END TO J933-20 & SPOT TIE TO EXISTING EXCITER HARNESS.
 - 5. INSTALL ORANGE WIRE PART OF PL19C851484G2 HARNESS IN P3-9 SOLDER OTHER END TO P8-20. INSTALL YELLOW WIRE PART OF PL19C851484G2 HARNESS IN P4-2 & SOLDER OTHER END TO P8-19. INSTALL WRBL WIRE PART OF PL19C851484G2 HARNESS IN P4-9 & SOLDER THE OTHER END TO P8-18. SPOT TIE THE PL19C851484G2 HARNESS TO EXISTING PL19C320811 HARNESS.
- THESE INSTRUCTIONS COVER THE INSTALLATION OF CABLE HARNESS PL19C851484G3 AND PL19B234841G1.
 - 1. DO STEPS 1 THRU 4 OF PART 2 ABOVE.
 - 2. INSTALL YELLOW WIRE PART OF PL19B23484161 HARNESS IN P1-1 SOLDER OTHER END TO P7-5. INSTALL WHITE-RED WIRE PART OF PL19B23484161 HARNESS IN P4-9 SOLDER OTHER END TO P8-18. INSTALL WHITE-BLUE-BLACK WIRE PART OF PL19B23484161 HARNESS IN P4-2 SOLDER OTHER END TO P8-19. INSTALL WHITE-ORANGE WIRE PART OF PL19B23484161 HARNESS IN P3-9 SOLDER OTHER END TO P8-20.
 - 3. SPOT TIE PL19B234841G1 TO EXISTING PL19C320811 HARNESS WITH CABLE CLAMPS SUPPLIED WITH PL19B234841G1 HARNESS.
- 800 MHz PST 19B234774G8
 - 1. INSTALL YELLOW WIRE IN P901-2 & SOLDER OTHER END TO J933-19.
 - 2. INSTALL W-O WIRE IN P901-15 AND SOLDER OTHER END TO J933-20. SPOT TIE YELLOW AND ORANGE WIRES TO EXISTING EXCITER HARNESS.
 - 3. REMOVE DA WIRE BETWEEN 1933-4 AND 1933-8.



MODIFICATIONS INSTRUCTIONS

VOICE GUARD APPLICATIONS